

Photocouplers GaAlAs Infrared LED & Photo IC

TLP2768B

1. Applications

- · Programmable Logic Controllers (PLCs)
- · Factory Automation (FA)
- · Measuring Instruments

2. General

The TLP2768B consists of a high-output light-emitting diode coupled with integrated high gain, high-speed photodetectors. The TLP2768B guarantees operation at up to 125 °C and on supplies from 2.7 V to 5.5 V. It is open drain output type and housed in the SO6L package. The TLP2768B supports slow inputs to the LED and the detector, eliminating the need to add components to suppress chattering noise and contributing to reduction of external circuit. The TLP2768B has an internal Faraday shield that provides a guaranteed common-mode transient immunity of $\pm 50~\rm kV/\mu s$.

3. Features

- (1) Inverter logic type (open drain output)
- (2) Package: SO6L
- (3) Operating temperature: -40 to 125 °C
- (4) Supply voltage: 2.7 to 5.5 V
- (5) Data transfer rate: 20 Mbps (typ.)
- (6) Threshold input current: 5.0 mA (max)
- (7) Supply current: 1 mA (max)
- (8) Common-mode transient immunity: ±50 kV/μs (min)
- (9) Isolation voltage: 5000 Vrms (min)
- (10) Safety standards

UL-recognized: UL 1577, File No.E67349

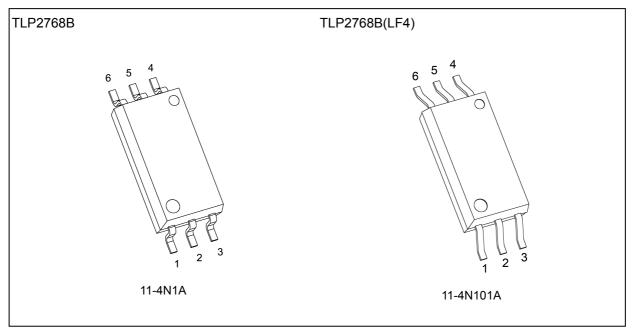
cUL-recognized: CSA Component Acceptance Service No.5A File No.E67349

VDE-approved: EN 60747-5-5, EN 62368-1 (Note 1) CQC-approved: GB4943.1, GB8898 Thailand Factory

Note 1: When a VDE approved type is needed, please designate the Option (D4).

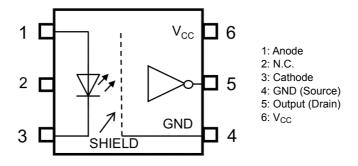


4. Packaging (Note)

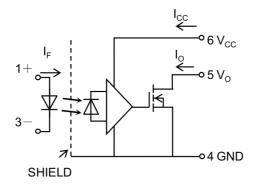


Note: Lead forming option: (LF4)

5. Pin Assignment



6. Internal Circuit (Note)



Note: A 0.1- μF bypass capacitor must be connected between pin 6 and pin 4.



7. Principle of Operation

7.1. Truth Table

Input	LED	Output
Н	ON	L
L	OFF	Н

7.2. Mechanical Parameters

Characteristics	Min	Unit
Creepage distances	8.0	mm
Clearance distances	8.0	
Internal isolation thickness	0.4	



8. Absolute Maximum Ratings (Note) (Unless otherwise specified, T_a = 25 °C)

	Characteristics		Symbol	Note	Rating	Unit
LED	Input forward current		I _F		25	mA
	Input forward current derating	(T _a ≥ 110 °C)	$\Delta I_F/\Delta T_a$		-0.67	mA/°C
	Input forward current (pulsed)		I _{FP}	(Note 1)	40	mA
	Input forward current derating (pulsed)	$(T_a \ge 110 ^{\circ}\text{C})$	$\Delta I_{FP}/\Delta T_a$		-1.0	mA/°C
	Peak transient input forward current		I _{FPT}	(Note 2)	1	А
	Peak transient input forward current derating	$(T_a \ge 110 ^{\circ}\text{C})$	$\Delta I_{FPT}/\Delta T_a$		-25	mA/°C
	Input power dissipation		P _D		55	mW
	Input power dissipation derating	$(T_a \ge 110 ^{\circ}\text{C})$	$\Delta P_D/\Delta T_a$		-1.92	mW/°C
	Input reverse voltage		V _R		5	V
Detector	Output current		Io		25	mA
	Output voltage		Vo		-0.5 to V_{CC}	V
	Supply voltage		V _{CC}		-0.5 to 6	
	Output power dissipation		Po		85	mW
	Output power dissipation derating	$(T_a \ge 110 ^{\circ}\text{C})$	$\Delta P_O/\Delta T_a$		0	mW/°C
Common	Operating temperature		T _{opr}		-40 to 125	°C
	Storage temperature		T _{stg}		-55 to 125	
	Lead soldering temperature	(10 s)	T _{sol}		260	
	Isolation voltage	(AC, 60 s, R.H. ≤ 60 %)	BV _S	(Note 3)	5000	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

- Note 1: Pulse width (PW) \leq 1 ms, duty = 50 %
- Note 2: Pulse width (PW) \leq 1 μ s, 300 pps
- Note 3: This device is considered as a two-terminal device: Pins 1, 2 and 3 are shorted together, and pins 4, 5 and 6 are shorted together.



9. Recommended Operating Conditions (Note)

Characteristics	Symbol	Note	Min	Тур.	Max	Unit
Input on-state current	I _{F(ON)}		7.5	_	14	mA
Input off-state voltage	V _{F(OFF)}		0	_	0.8	V
Rise time of I _F	t _{r(IF)}	(Note 1)	5 n	_	60	s
Fall time of I _F	t _{f(IF)}	(Note 2)	5 n	_	60	
Supply voltage	V _{CC}	(Note 5)	2.7	3.3 / 5.0	5.5	٧
Rise time of V _{CC}	t _{r(VCC)}	(Note 3)	10 μ	_	60	s
Fall time of V _{CC}	t _{f(VCC)}	(Note 4)	10 μ	_	60	
Operating temperature	T _{opr}	(Note 5)	-40	_	125	°C

Note: The recommended operating conditions are given as a design guide necessary to obtain the intended performance of the device. Each parameter is an independent value. When creating a system design using this device, the electrical characteristics specified in this data sheet should also be considered.

Note: A ceramic capacitor $(0.1 \, \mu F)$ should be connected between pin 4 and pin 6 to stabilize the operation of a high-gain linear amplifier. Otherwise, this photocoupler may not switch properly. The bypass capacitor should be placed within 1 cm of each pin.

- Note 1: The rise time of input forward current which takes for linear increase from 0 mA to 7.5 mA.
- Note 2: The fall time of input forward current which takes for linear decrease from 7.5 mA to 0 mA.
- Note 3: The rise time of supply voltage which takes for linear increase from 0 V to 2.7 V.
- Note 4: The fall time of supply voltage which takes for linear decrease from 2.7 V to 0 V.
- Note 5: Denotes the operating range, not the recommended operating condition.

Electrical Characteristics (Note) (Unless otherwise specified, T_a = -40 to 125 °C, V_{CC} = 2.7 to 5.5 V)

Characteristics	Symbol	Test Circuit	I Test Condition I		Тур.	Max	Unit
Input forward voltage	V _F		I _F = 10 mA, T _a = 25 °C	1.45	1.57	1.70	V
Input forward voltage temperature coefficient	$\Delta V_F/\Delta T_a$		I _F = 10 mA	_	-1.3	_	mV/°C
Input reverse current	I _R		V _R = 5 V, T _a = 25 °C	_	_	10	μΑ
Input capacitance	Ct		V _S = 0 V, f = 1 MHz, T _a = 25 °C	_	38	_	pF
High-level output current	I _{OH}	Fig.13.1.1	$V_F = 0.8 \text{ V}, V_O = 5.5 \text{ V}$ $V_{CC} = 5.5 \text{ V}$	_	_	50	μА
			$V_F = 0.8 \text{ V}, V_O = 5.5 \text{ V}$ $V_{CC} = 5.5 \text{ V}, T_a = 25 ^{\circ}\text{C}$	_	_	10	
Low-level output voltage	V _{OL}	Fig.13.1.2	Fig.13.1.2 I _F = 10 mA I _O = 13 mA (Sinking)		0.2	0.6	V
High-level supply current	I _{CCH}	Fig.13.1.3	I _F = 0 mA	_	0.6	1.0	mA
Low-level supply current	I _{CCL}	Fig.13.1.4	I _F = 10 mA	_	0.7	1.0	
Threshold input current (H/L)	I _{FHL}	Fig.13.1.5	I _O = 13 mA (Sinking) V _O < 0.6 V	_	1.2	5.0	
Threshold input current (L/H)	I _{FLH}		I _O = 13 mA (Source) V _O < 0.6 V	0.5	1.0	_	
Input current hysteresis	I _{HYS}	1	I _{FHL} - I _{FLH}	_	0.2	_	

Note: All typical values are at V_{CC} = 5 V, T_a = 25 °C.

11. Isolation Characteristics (Unless otherwise specified, T_a = 25 °C)

Characteristics	Symbol	Note	Test Condition	Min	Тур.	Max	Unit
Total capacitance (input to output)	Cs	(Note 1)	V _S = 0 V, f = 1 MHz	_	0.4	_	pF
Isolation resistance	R _S	(Note 1)	V _S = 500 V, R.H. ≤ 60 %	1012	1014	_	Ω
Isolation voltage	BV _S	(Note 1)	AC, 60 s	5000	-	_	Vrms

Note 1: This device is considered as a two-terminal device: Pins 1, 2 and 3 are shorted together, and pins 4, 5 and 6 are shorted together.



12. Switching Characteristics (Note) (Unless otherwise specified, $T_a = -40$ to 125 °C, $V_{CC} = 2.7$ to 5.5 V)

Characteristics	Symbol	Note	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Propagation delay time (H/L)	t _{pHL}	(Note 1)	Fig.13.1.6	I_F = 0 \rightarrow 7.5 mA, R_L = 350 Ω C_L = 15 pF,	_	30	60	ns
Propagation delay time (L/H)	t _{pLH}	(Note 1)		I_F = 7.5 \rightarrow 0 mA, R_L = 350 Ω C_L = 15 pF,	_	34	60	
Pulse width distortion	t _{pHL} -t _{pLH}	(Note 1)		I_F = 7.5 mA, R_L = 350 $Ω$ C_L = 15 pF,	_	4	35	
Propagation delay skew (device to device)	t _{psk}	(Note 1), (Note 2)		I_F = 7.5 mA, R_L = 350 $Ω$ C_L = 15 pF,	-35	_	35	
Fall time	t _f	(Note 1)		I_F = 0 \rightarrow 7.5 mA, R_L = 350 Ω C_L = 15 pF,	_	1	_	
Rise time	t _r	(Note 1)		I_F = 7.5 \rightarrow 0 mA, R_L = 350 Ω C_L = 15 pF,	_	14	_	
High-level common-mode transient immunity	CM _H		Fig.13.1.7	V_{CM} = 1000 V_{p-p} I_F = 0 mA, V_{CC} = 2.7 V / 5.5 V, T_a = 25 °C	±50	_	_	kV/μs
Low-level common-mode transient immunity	CML			V_{CM} = 1000 V_{p-p} I_F = 10 mA, V_{CC} = 2.7 V / 5.5 V, T_a = 25 °C	±50	_	_	

Note: All typical values are at V_{CC} = 5 V, T_a = 25 °C.

Note 1: f = 5 MHz, duty = 50 %, input current $t_r = t_f = 5$ ns, C_L is approximately 15 pF which includes probe and stray wiring capacitance.

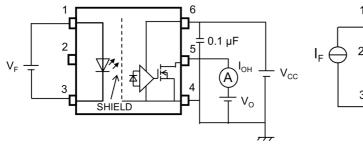
Note 2: The propagation delay skew, t_{psk} , is equal to the magnitude of the worst-case difference in t_{phl} and/or t_{plh} that will be seen between units at the same given conditions (supply voltage, input current, temperature, etc).

Rev.3.0



13. Test Circuits and Characteristics Curves

13.1. Test Circuits



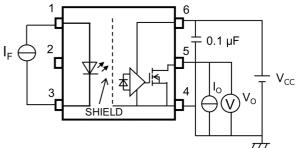


Fig. 13.1.1 I_{OH} Test Circuit

Fig. 13.1.2 V_{OL} Test Circuit

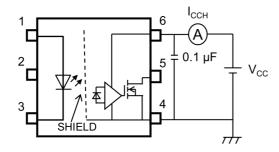


Fig. 13.1.3 I_{CCH} Test Circuit

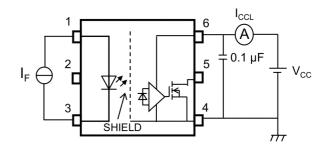


Fig. 13.1.4 I_{CCL} Test Circuit

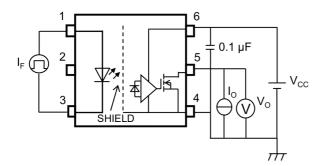


Fig. 13.1.5 I_{FHL}, I_{FLH}, I_{HYS} Test Circuit

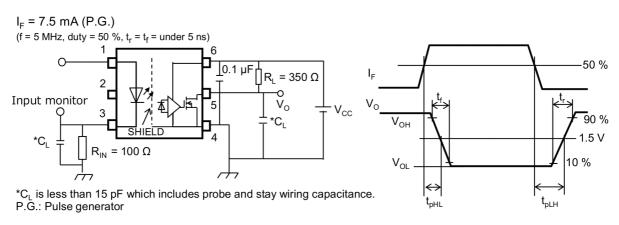


Fig. 13.1.6 Switching Time Test Circuit and Waveform



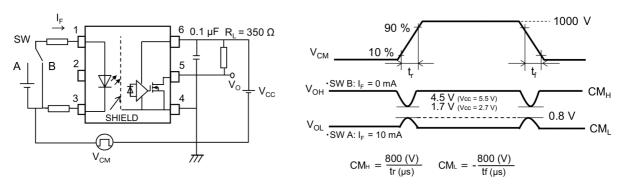


Fig. 13.1.7 Common-Mode Transient Immunity and Waveform



13.2. Characteristics Curves (Note)

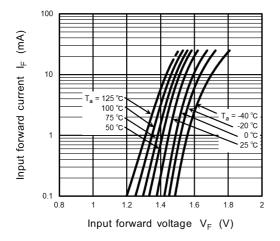


Fig. 13.2.1 I_F - V_F

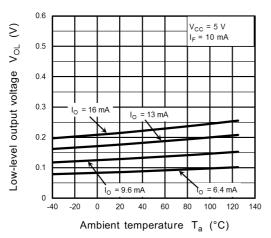


Fig. 13.2.3 V_{OL} - T_a

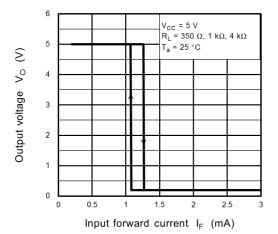


Fig. 13.2.5 V_O - I_F

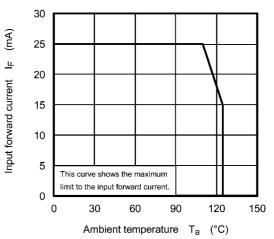


Fig. 13.2.2 I_F - T_a

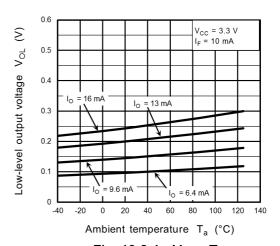


Fig. 13.2.4 V_{OL} - T_a

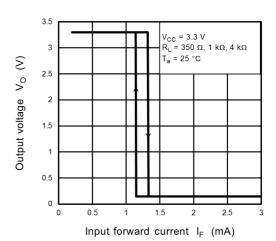


Fig. 13.2.6 V_O - I_F



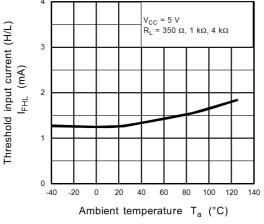


Fig. 13.2.7 I_{FHL} - T_a

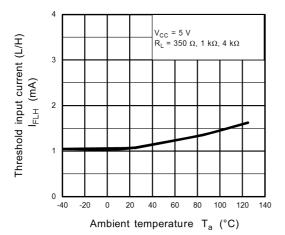


Fig. 13.2.9 I_{FLH} - T_a

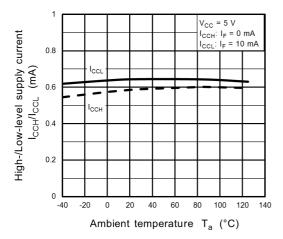


Fig. 13.2.11 I_{CCH}, I_{CCL} - Ta

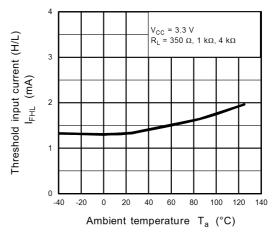


Fig. 13.2.8 I_{FHL} - T_a

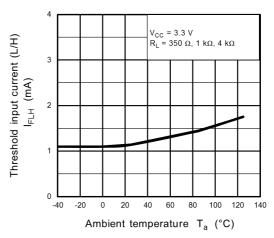


Fig. 13.2.10 I_{FLH} - T_a

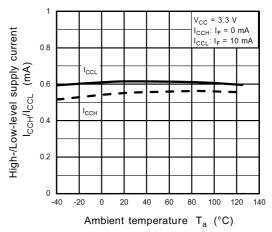


Fig. 13.2.12 I_{CCH}, I_{CCL} - Ta



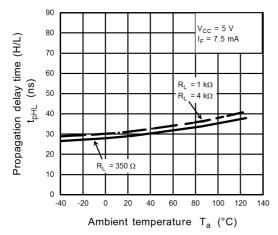


Fig. 13.2.13 t_{pHL} - T_a

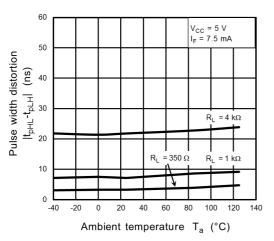


Fig. 13.2.15 $|t_{pHL} - t_{pLH|} - T_a$

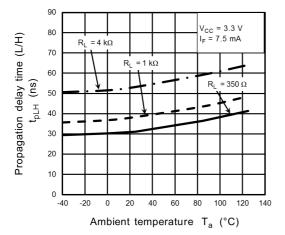


Fig. 13.2.17 t_{pLH} - T_a

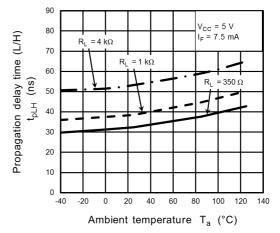


Fig. 13.2.14 t_{pLH} - T_a

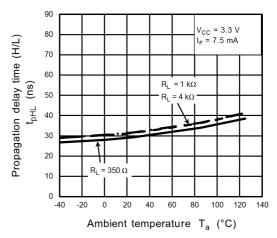


Fig. 13.2.16 t_{pHL} - T_a

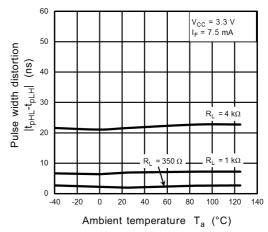
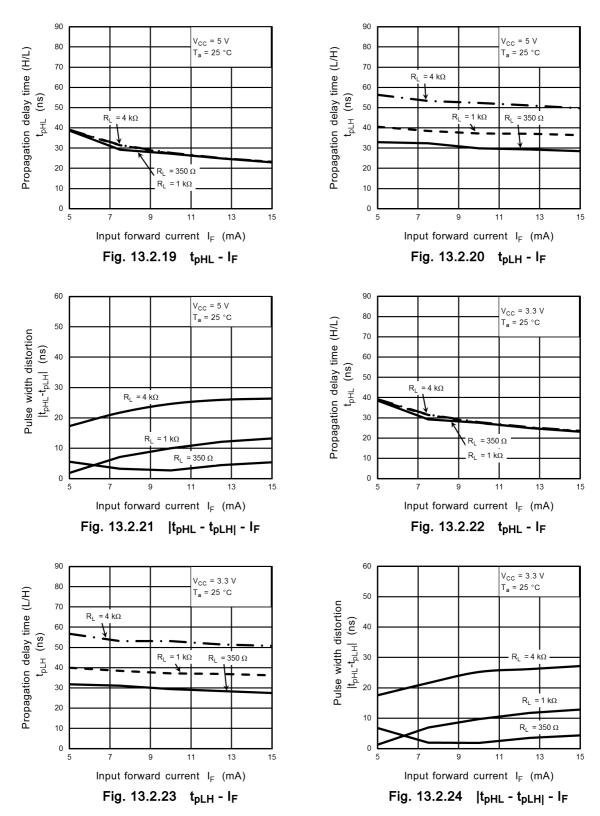


Fig. 13.2.18 $|t_{pHL} - t_{pLH|} - T_a$





Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



14. Soldering and Storage

14.1. Precautions for Soldering

The soldering temperature should be controlled as closely as possible to the conditions shown below, irrespective of whether a soldering iron or a reflow soldering method is used.

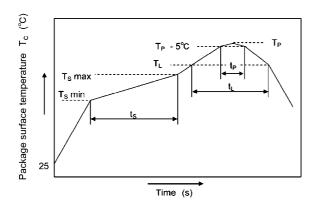
· When using soldering reflow.

The soldering temperature profile is based on the package surface temperature.

(See the figure shown below, which is based on the package surface temperature.)

Reflow soldering must be performed once or twice.

The mounting should be completed with the interval from the first to the last mountings being 2 weeks.



	Symbol	Min	Max	Unit
Preheat temperature	Ts	150	200	°C
Preheat time	ts	60	120	S
Ramp-up rate (T _L to T _P)			3	°C/s
Liquidus temperature	TL	217		°C
Time above T _L	t _L	60	150	S
Peak temperature	T _P		260	°C
Time during which T_c is between $(T_P - 5)$ and T_P	t _P		30	s
Ramp-down rate (T _P to T _L)			6	°C/s

Fig. 14.1.1 An Example of a Temperature Profile When Lead(Pb)-Free Solder Is Used

· When using soldering flow

Preheat the device at a temperature of 150 °C (package surface temperature) for 60 to 120 seconds. Mounting condition of 260 °C within 10 seconds is recommended.

Flow soldering must be performed once.

· When using soldering Iron

Complete soldering within 10 seconds for lead temperature not exceeding 260 °C or within 3 seconds not exceeding 350 °C

Heating by soldering iron must be done only once per lead.

14.2. Precautions for General Storage

- · Avoid storage locations where devices may be exposed to moisture or direct sunlight.
- Follow the precautions printed on the packing label of the device for transportation and storage.
- Keep the storage location temperature and humidity within a range of 5 °C to 35 °C and 45 % to 75 %, respectively.
- Do not store the products in locations with poisonous gases (especially corrosive gases) or in dusty conditions.
- Store the products in locations with minimal temperature fluctuations. Rapid temperature changes during storage can cause condensation, resulting in lead oxidation or corrosion, which will deteriorate the solderability of the leads.
- · When restoring devices after removal from their packing, use anti-static containers.
- · Do not allow loads to be applied directly to devices while they are in storage.
- If devices have been stored for more than two years under normal storage conditions, it is recommended that you check the leads for ease of soldering prior to use.



15. Land Pattern Dimensions (for reference only)

Unit: mm

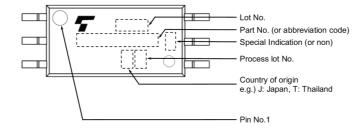
TLP2768B (LF4)

1.27

Fig. 15.1 Lead Forming Option (standard)

Fig. 15.2 Lead Forming Option (LF4)

16. Marking



Part number:TLP2768B



17. EN 60747-5-5 Option (D4) Specification

· Part number: TLP2768B (Note 1)

• The following part naming conventions are used for the devices that have been qualified according to option (D4) of EN 60747.

Example: TLP2768B(D4-TP,E

D4: EN 60747 option

TP: Tape type

E: [[G]]/RoHS COMPATIBLE (Note 2)

Note 1: Use TOSHIBA standard type number for safety standard application.

e.g., TLP2768B(D4-TP,E \rightarrow TLP2768B

Note 2: Please contact your Toshiba sales representative for details on environmental information such as the product's RoHS compatibility.

RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

Description	Symbol	Rating	Unit
Application classification for rated mains voltage ≤ 600 Vrms for rated mains voltage ≤ 1000 Vrms		I-IV I-III	_
Climatic classification		40 / 125 / 21	_
Pollution degree		2	_
Maximum operating insulation voltage	VIORM	1500	Vpeak
Input to output test voltage, Method A V_{pr} = 1.6 × VIORM, type and sample test t_p = 10 s, partial discharge < 5 pC	Vpr	2400	Vpeak
Input to output test voltage, Method B Vpr =1.875 × Viorm, 100 % production test tp = 1 s, partial discharge < 5 pC	Vpr	2813	Vpeak
Highest permissible overvoltage (transient overvoltage, tpr = 60 s)	VTR	8000	Vpeak
Safety limiting values (max. permissible ratings in case of fault, also refer to thermal derating curve) current (input current IF, P_{SO} = 0) power (output or total power dissipation) temperature	I _{si} Pso Ts	300 700 150	mA mW °C
Insulation resistance $VIO = 500 \text{ V}, T_a = 25 \text{ °C}$ $VIO = 500 \text{ V}, T_a = 100 \text{ °C}$ $VIO = 500 \text{ V}, T_a = T_s$	Rsi	≥ 10 ¹² ≥ 10 ¹¹ ≥ 10 ⁹	Ω

Fig. 17.1 EN 60747 Isolation Characteristics



Minimum creepage distance	Cr	8.0 mm
Minimum clearance	CI	8.0 mm
Minimum insulation thickness	ti	0.4 mm
Comparative tracking index	СТІ	500

Fig. 17.2 Insulation Related Specifications (Note)

Note: This photocoupler is suitable for **safe electrical isolation** only within the safety limit data. Maintenance of the safety data shall be ensured by means of protective circuits.



Fig. 17.3 Marking on Packing

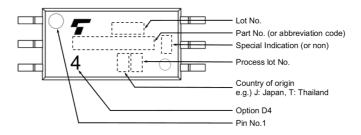


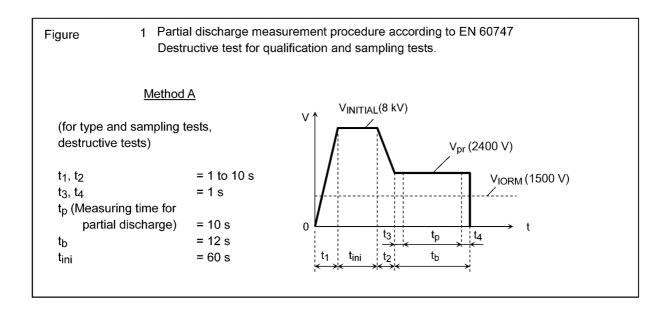
Fig. 17.4 Marking Example (Note)

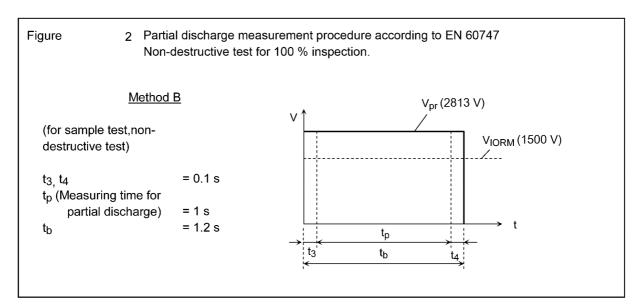
Note: The above marking is applied to the photocouplers that have been qualified according to option (D4) of EN

60747.

Part No.: TLP2768B







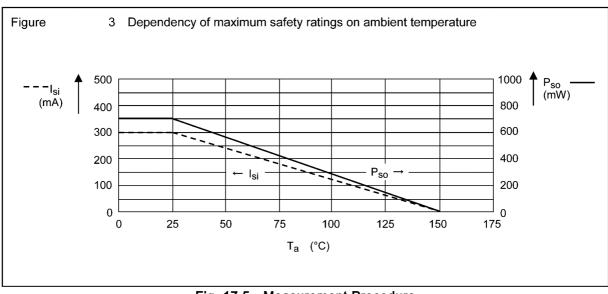


Fig. 17.5 Measurement Procedure



18. Ordering Information

When placing an order, please specify the part number, tape type and quantity as shown in the following example.

Example: TLP2768B(TP,E 1500 pcs

Part number: TLP2768B

Tape type: TP

[[G]]/RoHS COMPATIBLE: E (Note)

Quantity (must be a multiple of 1500): 1500 pcs

Note: Please contact your Toshiba sales representative for details on environmental information such as the product's

RoHS compatibility.

RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the

restriction of the use of certain hazardous substances in electrical and electronic equipment.

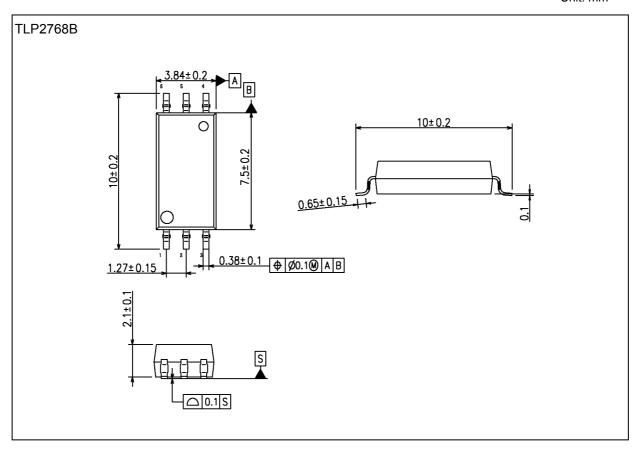
19. Ordering Information (Example of Item Name)

Item Name	Packaging	VDE Option	Packing (MOQ)
TLP2768B(E			Magazine (125 pcs)
TLP2768B(TP,E			Tape and reel (1500 pcs)
TLP2768B(D4,E		EN 60747-5-5	Magazine (125 pcs)
TLP2768B(D4-TP,E		EN 60747-5-5	Tape and reel (1500 pcs)
TLP2768B(LF4,E	LF4, Wide forming		Magazine (125 pcs)
TLP2768B(TP4,E	LF4, Wide forming		Tape and reel (1500 pcs)
TLP2768B(D4LF4,E	LF4, Wide forming	EN 60747-5-5	Magazine (125 pcs)
TLP2768B(D4TP4,E	LF4, Wide forming	EN 60747-5-5	Tape and reel (1500 pcs)



Package Dimensions

Unit: mm



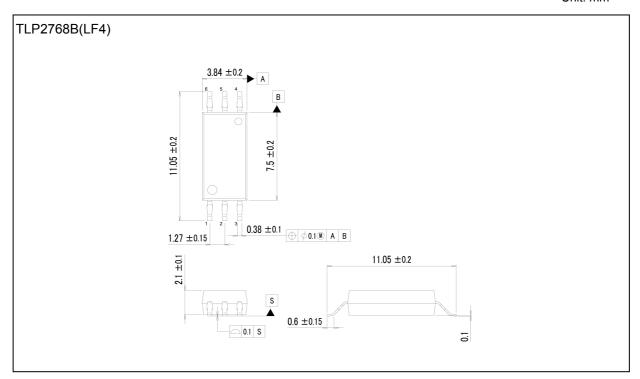
Weight: 0.126 g (typ.)

	Package Name(s)
TOSHIBA: 11-4N1A	



Package Dimensions

Unit: mm



Weight: 0.126 g (typ.)

Package Name(s)
TOSHIBA: 11-4N101A



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